

6367254 MOTOROLA SC (XSTRS/R F)

96D 80565 DT-33-19

MOTOROLA
SEMICONDUCTOR
TECHNICAL DATA

BD186
BD188
BD190

**PLASTIC MEDIUM POWER
SILICON PNP TRANSISTOR**

... designed for use in 5 to 10 Watt audio amplifiers utilizing complementary or quasi complementary circuits.

- DC Current $h_{FE} = 40$ (Min) @ $I_C = 0.5$ Adc
- BD 186, 188, 190 are complementary with BD 185, 187, 189

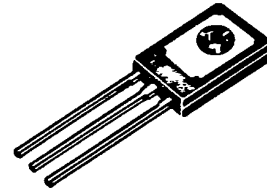
**4 AMPERE
POWER TRANSISTOR**

PNP SILICON

**30, 45, 60 VOLTS
40 WATTS**

MAXIMUM RANGS

Rating	Symbol	Type	Value	Unit
Collector-Emitter Voltage	V_{CEO}	BD 186 BD 188 BD 190	30 45 60	Vdc
Collector-Base Voltage	V_{CBO}	BD 186 BD 188 BD 190	40 55 70	Vdc
Emitter-Base Voltage	V_{EBO}		5	Vdc
Collector Current	I_C		4.0	Adc
Base Current	I_B		2.0	Adc
Total Device Dissipation $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D		40 320	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}		-65 to +150	$^\circ\text{C}$



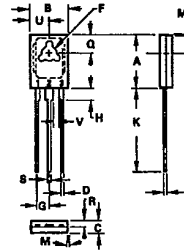
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	3.12	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Type	Min	Max	Unit
Collector-Emitter Sustaining Voltage* ($I_C = 0.1$ Adc, $I_B = 0$)	BV_{CEO}	BD 186 BD 188 BD 190	30 45 60	—	Vdc
Collector Cutoff Current ($V_{CB} = 40$ Vdc, $I_E = 0$) ($V_{CB} = 55$ Vdc, $I_E = 0$) ($V_{CB} = 70$ Vdc, $I_E = 0$)	I_{CBO}	BD 186 BD 188 BD 190	— — —	0.1 0.1 0.1	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0$ Vdc, $I_C = 0$)	I_{EBO}		—	1.0	mAdc
DC current Gain ($I_C = 0.5$ A, $V_{CE} = 2$ V) ($I_C = 2$ A, $V_{CE} = 2$ V)	h_{FE}		40 15	—	
Collector-Emitter Saturation Voltage* ($I_C = 2.0$ Adc, $I_B = 0.2$ Adc)	$V_{CE(sat)}$		—	1.0	Vdc
Base-Emitter On Voltage* ($I_C = 2.0$ Adc, $V_{CE} = 2.0$ Vdc)	$V_{BE(on)}$		—	1.5	Vdc
Current-Gain-Bandwidth Product ($I_C = 1.0$ Adc, $V_{CE} = 10$ Vdc, $f = 1.0$ MHz)	f_T		2.0	—	MHz

* Pulse Test: Pulse Width ≤ 300 μs . Duty Cycle $\leq 2.0\%$.



MILLIMETERS		INCHES	
DIM	MIN - MAX	MIN - MAX	
A	5.00 11.00	0.20 0.43	0.25
B	2.98 3.74	0.29 0.35	0.32
C	2.42 2.86	0.09 0.11	0.10
D	0.11 0.88	0.00 0.03	0.015
E	2.92 3.17	0.11 0.12	0.11
F	2.32 2.88	0.09 0.11	0.09
G	2.72 3.41	0.10 0.13	0.11
H	2.92 3.17	0.11 0.12	0.11
I	11.81 11.92	0.47 0.47	0.47
J	2.72	0.11	0.11
K	3.18 4.11	0.12 0.16	0.14
L	1.18 1.28	0.05 0.05	0.05
M	0.14 0.28	0.005 0.01	0.005
N	2.88 3.92	0.11 0.15	0.13
V	1.02	—	0.04

STYLE 1
1. PNP - EMITTER
2. COLLECTOR
3. BASE

NOTES:
1. M1 - MAIN TERMINAL
2. LEADS MUST BE POSITIONED WITHIN 2 DEGREE BE CH
3. ALL DIMENSIONS ARE AT MAXIMUM MATERIAL
CONDITION.

**CASE 77-05
TO-126**

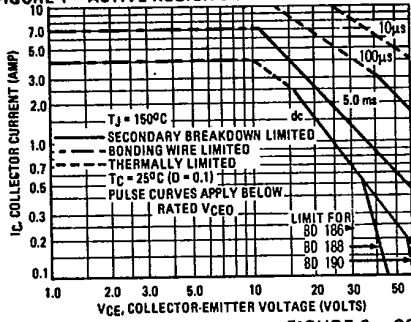
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BD186, BD188, BD190

T-33-19

FIGURE 1 - ACTIVE-REGION SAFE OPERATING AREA



The Safe Operating Area Curves indicate I_C - V_{CE} limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power-temperature derating must be observed for both steady state and pulse power conditions.

FIGURE 2 - COLLECTOR SATURATION REGION

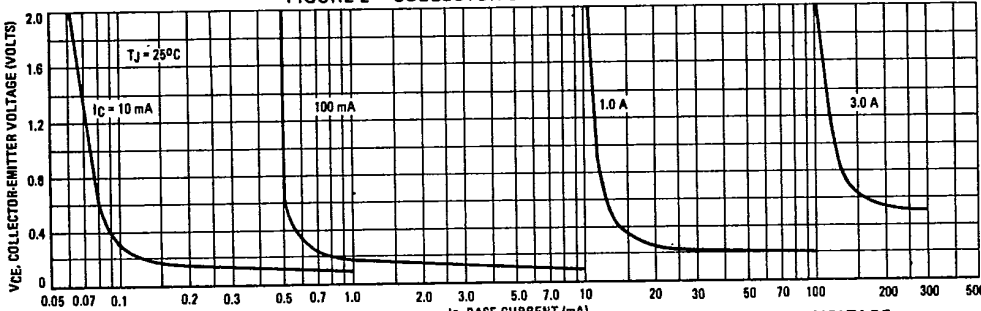


FIGURE 3 - NORMALIZED DC CURRENT GAIN

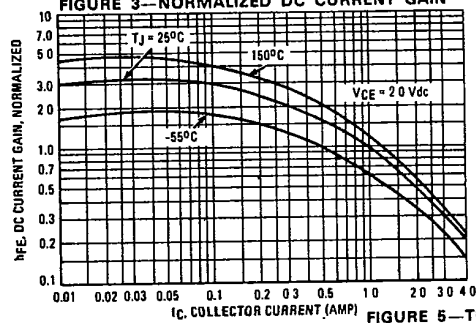


FIGURE 4 - "ON" VOLTAGE

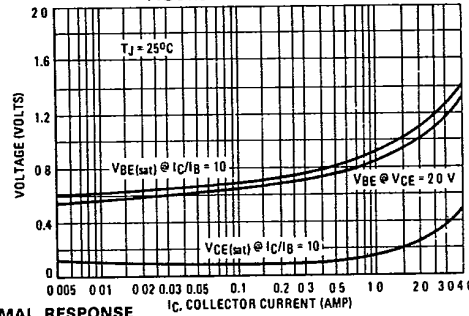


FIGURE 5 - THERMAL RESPONSE

